

A comparative study of heterostructured CuO/CuWO₄ nanowires and thin films

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Abstract. A comparative study of heterostructured CuO/CuWO₄ core/shell nanowires and double-layer thin films was performed through X-ray diffraction, confocal micro-Raman spectroscopy and electron (SEM and TEM) microscopies. The heterostructures were produced using a two-step process, starting from a deposition of amorphous WO₃ layer on top of CuO nanowires and thin films by reactive DC magnetron sputtering and followed by annealing at 650°C in air. The second step induced a solid-state reaction between CuO and WO₃ oxides through a thermal diffusion process, revealed by SEM-EDX analysis. Morphology evolution of core/shell nanowires and double-layer thin films upon heating was studied by electron (SEM and TEM) microscopies. A formation of CuWO₄ phase was confirmed by X-ray diffraction and confocal micro-Raman spectroscopy.

Keywords:

A1. Characterization

A1. Crystal morphology

A1. Nanostructures

B1. Oxides

B1. Tungstates

1. Introduction

Metal oxide nanowires (NWs) and their heterostructures are promising materials for the next generation of solar power harvesting devices [1,2], photocatalyst materials for water splitting [3,4] and gas sensing devices [5]. The use of axially heterostructured or core/shell NWs has several important advantages in comparison to thin film technologies: combination of materials with large lattice mismatch and even epitaxial growth of shell material on the core, improved mechanical properties due to a reduction in the number of defects per unit length, superior electroconductive properties of NWs due to their crystallinity and small defect concentration, large surface area and/or large heterojunction area, novel or significantly improved thermal, optical, electronic or field emission properties [6-10].

CuO nanowires can be produced in large quantities by simple and cost effective route of thermal oxidation of metallic copper or copper foil in air atmosphere [11]. A number of heterostructured core/shell NWs with CuO core were prepared and studied during last years.

The p-n CuO/ZnO heterojunction NWs were produced by thermal oxidation of copper and subsequent zinc oxide layer formation by atomic layer deposition [12] or thermal decomposition of zinc acetate [8, 13]. ZnO has a relatively large direct band gap of ~3.3 eV, similar to TiO₂ commonly used for photoelectrodes, but significantly enhanced electron mobility [14, 15]. Its combination with CuO, that has a narrow indirect band gap (1.2-1.4 eV), allows enhancing of light absorption in the solar spectrum region and solar conversion efficiency [8,13]. The sensing properties of CuO/ZnO NWs show higher sensitivity for reducing gases than those of pure CuO NWs [12]. Another successful application of CuO/ZnO NWs for solar energy harvesting and for hydrogen generation from photoelectrochemical water decomposition was demonstrated in [8, 13].

CuO/Co₃O₄ coaxial heterostructures, prepared by hydrothermal method, were studied in [16]. It was found that their morphology plays an important role in photocatalytic properties. In particular, coaxial heterostructures show higher photocatalytic efficiency under solar light irradiation compared with pure CuO nanorods and Co₃O₄ nanoflowers [16].

At the same time, the morphology of the CuO-core NWs can be often undesirably affected and totally disrupted by shell coating. For example, the coverage of straight CuO NWs with smooth surface by TiO₂-shell using metalorganic chemical vapour deposition technique led to NWs winding and roughening even at moderate substrate temperature 350°C [17]. Often NWs undergo severe shape and morphology degradation, or lose their integrity during chemical reactions in solid state [18,19]. This phenomenon of core degradation in CuO NWs is linked with diffusion of copper or oxygen atoms during chemical reaction and process of shell formation, and needs further investigation.

Recently CuO/CuWO₄ core/shell NW arrays were proposed as well-consisted system with enhanced activity and durability for photoelectrochemical water splitting (PEC) [20]. Pure CuWO₄ is a promising photoanode material, having electronic structure close to ideal for PEC water splitting [20-24]. It has n-type conductivity [25] with the indirect band gap in the range of 1.9-2.3 eV [26, 27, 28, 29, 30, 31]. CuWO₄ layer was produced on top of CuO NW array in solid-state chemical reaction employing hot wire chemical vapour deposition technique using tungsten and copper wires as a source of both tungsten oxide and copper/copper oxide vapours. The underlying CuO nanowires become essentially pure Cu₂O after deposition. It was shown [20] that the presence of CuWO₄ shell improves the photocurrents of Cu₂O NWs by improving their phase purity and charge separation due to the formation of a high-quality p-n heterojunction. However, no data of internal morphology of heterostructured NWs was provided in [20].

p-CuO/n-CuWO₄ heterojunction thin films were prepared recently using a multi-step process [32]. First, copper film was electrodeposited and annealed in air to obtain CuO film. Next, CuWO₄ layer was produced by spin-coating of tungstic acid and subsequent annealing at 500°C for 2 h in air. However, such synthesis approach resulted in largely irregular morphology of the heterojunction layer [32].

In this study, we investigated the formation mechanism and morphology evolution of two structures – 1D CuO/CuWO₄ core/shell NWs and 2D double-layer CuO/CuWO₄ thin films

prepared by reactive DC magnetron sputtering and post annealing in air. A comparison of two structures was performed in order to understand the mechanism of CuWO₄ phase formation upon annealing. Note that due to technical difficulties it is challenging to compare the same nanowire before and after annealing, while compositional and morphological analysis of thin film cross section before and after annealing is straightforward. X-ray diffraction (XRD), electron microscopy methods, confocal micro-Raman spectroscopy and spatial energy dispersive X-ray (EDX) analysis allowed us to figure out details of CuWO₄ formation process. To the best of our knowledge, this is the first comparison of a transformation from CuO/WO₃ to CuO/CuWO₄ in core/shell NWs and thin films upon heating.

2. Experimental details

Core/shell nanowire synthesis (sample type 1). An array of CuO NWs was grown by heating copper foil at 450°C in a high temperature oven (Carbolite HTF 17/5) over a period of two hours [33]. Synthesized NWs were 10-20 μm long, with diameters in the range of 30 to 150 nm. Then the array of CuO NWs was coated by a layer (100 nm on flat substrate) of amorphous WO₃ using reactive DC magnetron sputtering at room temperature of metallic tungsten target in mixed Ar(80%)-O₂(20%) atmosphere [34] (sample type 1, Fig. 1). Core/shell CuO/WO₃ NWs samples were annealed for two hours at 650°C to induce a formation of CuWO₄ shell via the solid-state reaction between CuO NW and amorphous WO₃ layer.

Double-layer thin film synthesis (sample type 2). Double-layer CuO/WO₃ thin film was deposited on Si(100) wafer substrate by reactive DC magnetron sputtering method consecutively from Cu (99.99%) and metallic W (99.95%) targets in mixed argon-oxygen atmosphere. The deposition was performed at a power of 200 W and a pressure of 20 mTorr. The target to substrate distance was about 9 cm, and the substrate was not heated intentionally. The Ar and O₂ gas flow rates were kept constant at 20 sccm and 10 sccm, respectively. Thus obtained WO₃/CuO/Si(100) sample (sample type 2, Fig. 1) was cut into two parts, and one part was heated in a horizontal tube

furnace at about 650°C for two hours in air to induce a reaction between the two oxide layers leading to a formation of CuWO₄.

Characterization. The crystallographic structure of heterostructured CuO/WO₃ NWs and double-layer thin films was characterized by X-ray diffraction (XRD). XRD measurements were carried out at room temperature using X-ray diffractometer X'Pert Pro Powder (PANalytical) with a Cu-K α source by scanning θ - θ in the range of 10-60°.

The morphology and elemental composition of amorphous WO₃-coated CuO NWs and annealed core/shell CuO/WO₃ NWs were studied using a high-resolution scanning electron microscope (SEM Lyra, Tescan) equipped with Oxford instruments energy dispersive X-ray (EDX) detector X-Max 50 mm² operated at 15 keV. The inner structure of core/shell NWs was investigated by a high-resolution transmission electron microscope (HRTEM Tecnai GF20, FEI) operated at an accelerating voltage of 180 kV.

Micro-Raman spectroscopy measurements were performed using a confocal microscope with spectrometer Nanofinder-S (SOLAR TII) [35]. Polycrystalline CuO and CuWO₄ powders were also measured for comparison. A diode pumped solid-state (DPSS) Nd:YAG laser (532 nm, max CW power P_{ex} =150 mW) was used as the excitation source. A continuous neutral filter with the optical density (OD) in the range of OD=0-3 was used to attenuate laser beam: OD=0 corresponds to about 12 mW at the sample. A Peltier-cooled back-thinned CCD camera (ProScan HS-101H) was used to register Raman scattering spectra. Hamamatsu R928 photomultiplier tube was employed in confocal-spectral imaging experiments. All measurements were performed in back-scattering geometry at room temperature (20°C) through a Nikon CF Plan Apo 100 \times (NA=0.95) optical objective.

3. Results and discussion

3.1. Structural analysis

XRD patterns were recorded for oxidized copper foil covered with CuO NWs (Fig. 2a). During oxidation process copper foil is covered by a layer of Cu₂O followed by the next layer of CuO film with protruding CuO NWs. Vertical orientation of CuO NWs is favourable for deposition of other materials (WO₃ in our case) by sputtering techniques. Bragg peaks positions for as grown CuO NWs sample are typical for such samples [36]. Metallic copper, CuO and Cu₂O can be identified in Fig. 2a. XRD pattern of WO₃ coated CuO NWs is identical to pure CuO NWs (not shown on the graph) due to amorphous structure of WO₃ layer. After annealing at 650°C in air for two hours the signal from metallic copper disappears due to all copper is oxidized but a new signal from CuWO₄ phase appears [37, 38].

XRD patterns of untreated and heated WO₃/CuO/Si(100) thin films are shown in Fig. 2b. A sharp peak with a shoulder at about $2\theta=33^\circ$ (labelled by asterisk in Fig. 2b) is a forbidden Si(200) reflection from the Si(100) wafer due to the multiple diffraction [39]. The pattern of a non-treated sample contains only CuO(11-1) broad peak indicating its textured nanocrystalline phase, whereas no evidence of WO₃ phase is present suggesting that it is in amorphous state, as expected. Upon heating at 650°C in air for two hours the crystallinity of CuO layer is improved, and the peak at 35.6° becomes less broadened. At the same time, a reaction between tungsten oxide and copper oxide layers occurs leading to a formation of CuWO₄ phase [37, 38].

3.2.Morphological analysis

A series of SEM images of pure CuO and WO₃-coated CuO NWs as well as core/shell CuO/WO₃ NWs annealed at 650°C in air are shown in Fig. 3. Pure CuO NWs have smooth faceted surface (Fig. 3a,b,c). After deposition of amorphous WO₃ layer a homogeneous shell is formed around CuO core with fine roughness (Fig. 3d). Further annealing of core/shell CuO/WO₃ NWs at 650°C leads to a crystallization of the outer shell and to a reaction between the core and the shell resulting in a formation of CuWO₄ phase (Fig. 3e-h).

An important question is how CuWO₄ is forming – either through Cu atoms diffusion into WO₃ layer or mutual interdiffusion of Cu and W atoms. Note that it is almost impossible to measure a change of CuO NW core diameter before and after annealing for the same CuO/WO₃ nanowire. However, in the case of double-layer CuO/WO₃ thin film it is possible to compare film thickness and morphology before and after annealing (Fig. 4). As-deposited CuO/WO₃ thin film before annealing has smooth surface (Fig. 4a), and in cross section, CuO and WO₃ layers are indistinguishable and appear as columnar and dense film (Fig. 4b). Annealed film has small voids and pores visible on the image from the top (Fig. 4e), and the two layers have clearly different morphology in cross section (Fig. 4f). Analysing EDX element maps of Cu and W atom distribution before and after annealing, one can see that tungsten atoms did not diffuse into CuO layer, while copper atoms moved into the tungsten oxide layer, thus giving origin to CuWO₄ phase (Fig. 4c,d,g,h).

More detailed information on the internal microstructure of the same set of NW samples was obtained by TEM microscopy (Fig. 5). Pure CuO NWs have a perfect crystalline structure (Fig. 5a,b) with the measured interplanar distance of ~2.5 Å, corresponding to the (11-1) plane of CuO. Our DC magnetron sputtering of tungsten in oxidizing atmosphere on a substrate maintained at room temperature produces an amorphous WO₃ film [34]. Therefore, WO₃ layer in as-prepared core/shell CuO/WO₃ NWs is amorphous as expected (Fig. 5c,d). The thickness of amorphous WO₃ layer averaged over several NWs was approximately 50 nm.

Crystallization of outer layer in core/shell NWs was observed upon annealing at 650°C (Fig. 5e,f). According to measured interplanar distance equal to 3.6 Å, the outer layer of NWs was identified as CuWO₄ phase with the (011) lattice planes [40,41]. This means that a solid-state reaction between amorphous WO₃ layer and CuO NW core occurred by thermal diffusion process. For comparison, monoclinic WO₃ [42] and W₁₈O₄₉ [43,44] nanowires have larger interplanar distances of about 3.8 Å for (001) and (010) planes, respectively. Upon annealing CuWO₄ crystals located around NWs core become self-assembled in a quasiperiodic manner (Fig. 5g,h). Note that

after annealing and formation of CuWO₄ crystals the CuO core remains single crystal phase and straight in shape (no voids are visible). Probably mostly copper atoms from the nanowire surface (as most mobile ones) move into WO₃ layer to form CuWO₄.

3.3. Raman spectroscopy

CuO [45], WO₃ [34] and CuWO₄ [46] crystalline phases can be easily distinguished according to their Raman response. Therefore, the use of confocal micro-Raman spectroscopy allowed us to access the phase composition of individual NWs and to follow their transformation upon annealing. Representative Raman spectra for individual as-prepared and annealed core/shell CuO/WO₃ NWs on silicon substrate, measured with full laser power (OD=0), are reported in Figs. 6b and 6d, respectively. Note that the first-order (~524 cm⁻¹) and second-order (~960 cm⁻¹) Raman bands from silicon substrate are also well observed, and their positions agree well with those from [47].

Raman scattering spectrum of pure CuO NW sample consists of phonon bands at 293 cm⁻¹ (A_g mode), 339 cm⁻¹ and 623 cm⁻¹ (B_g modes) in agreement with [48,49] and also with bulk CuO [45]. The position of the main band at 293 cm⁻¹ is strongly temperature-dependent [50]; therefore, its red-shift by ~22 cm⁻¹ and broadening in polycrystalline CuO powder and core/shell CuO/WO₃ NWs is caused by local laser heating (Fig. 6d).

Raman scattering spectra of core/shell CuO/WO₃ NWs are dominated by a contribution from CuWO₄ phase (Fig. 6b,d). Crystalline CuWO₄ has triclinic structure (space group *P-1*, *Z*=2) [51] composed of CuO₆ and WO₆ octahedra, distorted by the first-order and second-order Jahn-Teller effects, respectively [29]. According to group theoretical analysis, 36 phonon modes are expected at the centre of Brillouin-zone in CuWO₄, and 18 of them are even Raman active A_g modes. The positions of Raman bands at 121, 218, 277, 309, 472, 730, 770 and 900 cm⁻¹ (Fig. 5b,d) agree well with those in bulk CuWO₄ [29,46]. The appearance of CuWO₄ phase in Raman spectrum of as-prepared sample is due to solid-state reaction between nanowire CuO core and WO₃ shell induced locally by laser heating. This fact agrees well with literature data, where formation of crystalline

CuWO₄ from mixture of copper and tungsten salts starts approximately at 200°C [31]. Note that the most pronounced Raman band at 900 cm⁻¹, related to symmetric stretching W–O vibration [29, 46], can be used as a fingerprint of CuWO₄ phase existence. Laser-induced formation of CuWO₄ opens the possibilities to modify locally core-shell nanowires by focused laser beam for a fabrication of nano-device prototypes.

As it was shown above by TEM and SEM, CuO core preserves its straight shape and single-crystalline structure after the formation of CuWO₄ shell. The work by Jun et al. [17] on the investigation of the synthesis of CuO/TiO₂ core-shell NWs demonstrated that CuO core loses its straight shape, and the resulting core-shell NWs are heavily deformed. A thorough study by Wu et al. [19] on the process of conversion of CuO NWs into Cu₂O NWs indicated that the core of a NW remains straight for a long time while Cu₂O nanocrystals grow on the NW walls. This fact gives evidence that the removal of a large number of atoms from NW core is not critical for preservation of straight shape of the core. In our system, CuO core was coated by continuous layer of amorphous WO₃, which converted into discontinuous CuWO₄ shell during annealing through diffusion route. It is possible that the discontinuous shell of CuWO₄ cannot generate stress strong enough to break CuO core in contrast to the continuous crystalline TiO₂ shell.

Raman scattering spectra of two WO₃/CuO/Si(100) samples are shown in Fig. 7. One should note that a care should be taken when measuring thin films due to a possibility of laser induced crystallization [33]. In fact, at low laser power (1.2 mW) the non-treated sample shows weak Raman activity, which is typical for amorphous WO₃ thin film [33]: only the band at 960 cm⁻¹ due to a symmetric stretching mode of short terminal W=O bonds [52] is visible. Upon increasing laser power up to 12 mW, the top WO₃-layer crystallises, and its Raman spectrum becomes similar to those of WO₃ thin film annealed at 400°C [53] and of nanocrystalline WO₃ with the crystallites size of about 16-35 nm [54, 55]: several bands are visible at 128, 183, 262, 322, 690-700, 804 and 960 cm⁻¹. The origin of these bands is due to the stretching modes of the bridging oxygens $\nu(\text{W-O-W})$ (the bands at 690-700 and 804 cm⁻¹), the bending (deformation) modes $\delta(\text{O-W-O})$ at 262

and 322 cm⁻¹ as well as the lattice modes at 128 and 183 cm⁻¹ [2]. The Raman scattering spectrum of annealed sample has reach structure: most bands, including the main one at 906 cm⁻¹, are attributed to bulk CuWO₄ phase [29]. However, there is also the band due to silicon substrate at 525 cm⁻¹ and some evidence of two bands due to CuO layer at 290 and 314 cm⁻¹ [56]. The latter two bands overlap strongly with the bands of CuWO₄. Thus, the Raman data agree with the results of XRD analysis and confirm formation of CuWO₄ phase upon high temperature annealing.

4. Conclusions

In this paper we present the results of a comparative study of heterostructured CuO/CuWO₄ core/shell nanowires and double-layer thin films, which were synthesised by a simple approach based on a two-step process. Amorphous WO₃ thin layer was deposited first on top of CuO nanowires or thin film by reactive DC magnetron sputtering of tungsten, and high temperature annealing was used next to induce a solid-state reaction between CuO and WO₃ resulting in a formation of CuWO₄ phase. Note that similar approach can be employed for a production of other heterostructured metal-oxide/tungstate systems, such as NiO/NiWO₄ and ZnO/ZnWO₄ [57,58].

The morphology evolution of heterostructured core/shell nanowires and thin films upon heating was studied by scanning and transmission electron microscopies. A formation of crystalline CuWO₄ phase around nanowires or at the thin film surface was observed upon annealing of CuO/WO₃ system at 650°C in air and is due to thermally stimulated diffusion of copper ions into outer WO₃ layer, as revealed by SEM-EDX analysis. Note that CuO nanowire core is able to provide sufficient amount of copper ions into the WO₃ shell to produce CuWO₄ and still preserves its integrity and straight shape. The emergence of CuWO₄ phase was confirmed by X-ray diffraction and confocal micro-Raman spectroscopy.

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Figures

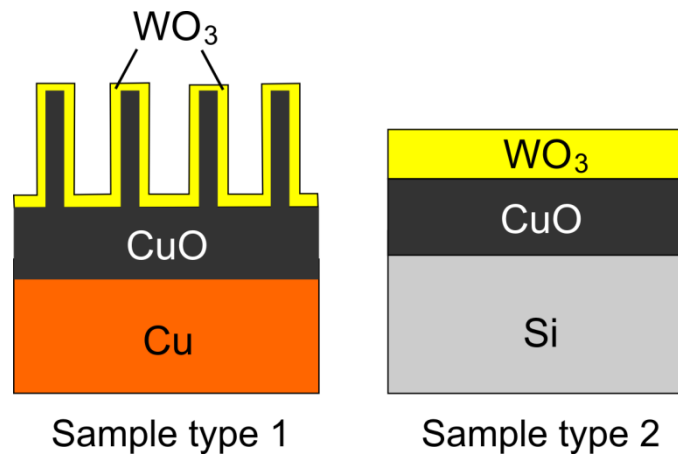


Fig. 1. Schematics of core-shell nanowire samples and double-layer thin film samples.

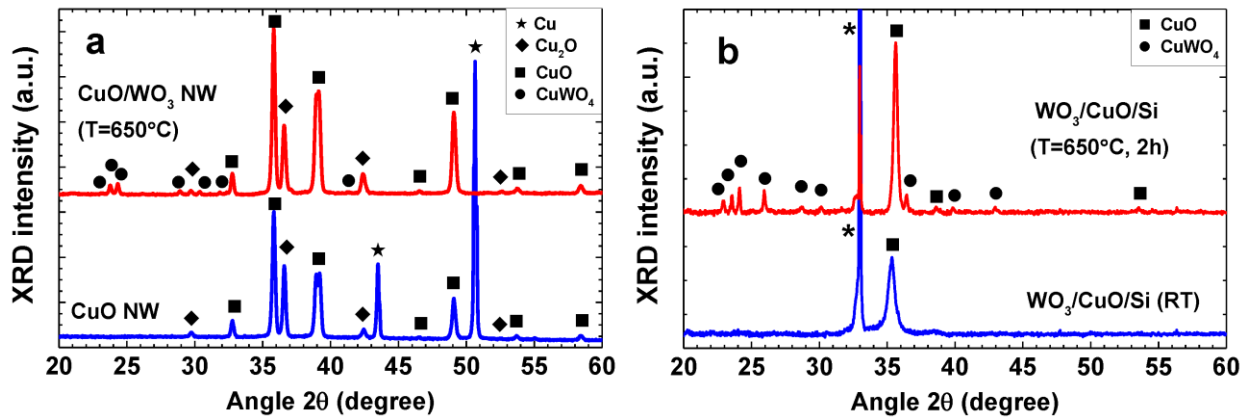


Fig. 2. XRD patterns of CuO NWs grown on Cu foil and CuO/WO₃ NWs annealed at 650°C (a), and CuO/WO₃ thin film before and after annealing at 650°C (b).

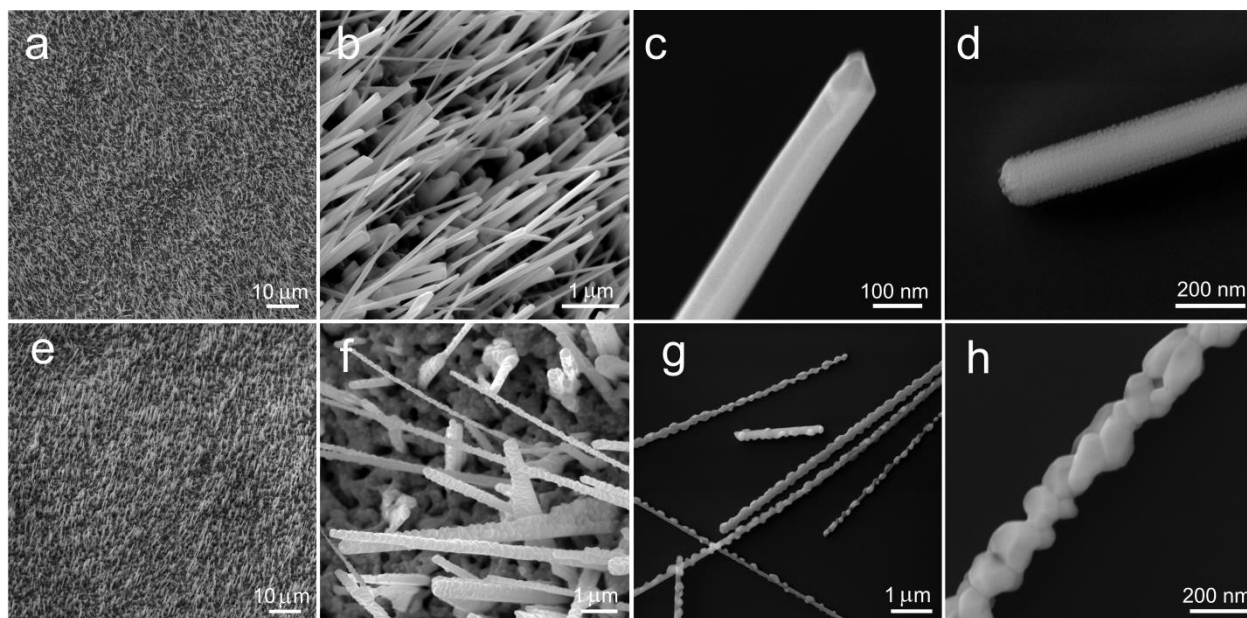


Fig. 3. SEM images of CuO NWs array on copper foil at lower (a) and higher magnification (b), individual CuO NW (c) and WO₃-coated CuO NW (d); core/shell CuO/WO₃ NWs array on copper foil annealed at 650°C at lower (e) and higher magnification (f). Core/shell CuO/WO₃ NWs on silicon substrate annealed at 650°C (g, h).

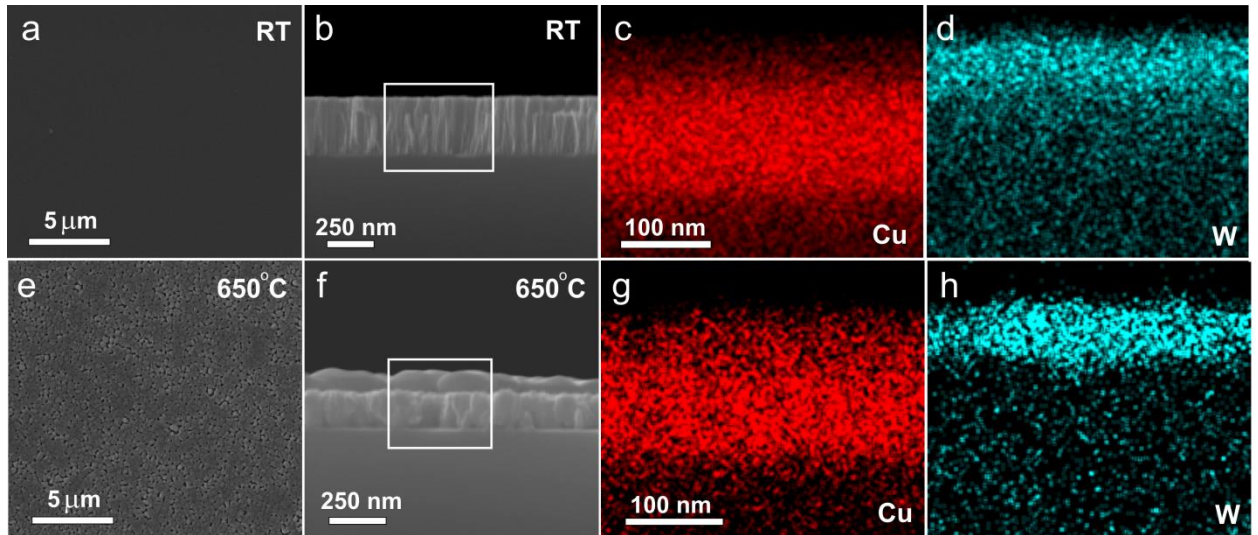


Fig. 4. SEM images of CuO/WO₃ thin film samples deposited on silicon wafer before annealing: top view (a), side view (b) and corresponding EDX maps of Cu and W atom distribution for the selected region (c and d). After annealing at 650° C: top view (e), side view (f) and corresponding EDX maps of Cu and W atom distribution for the selected region (g and h).

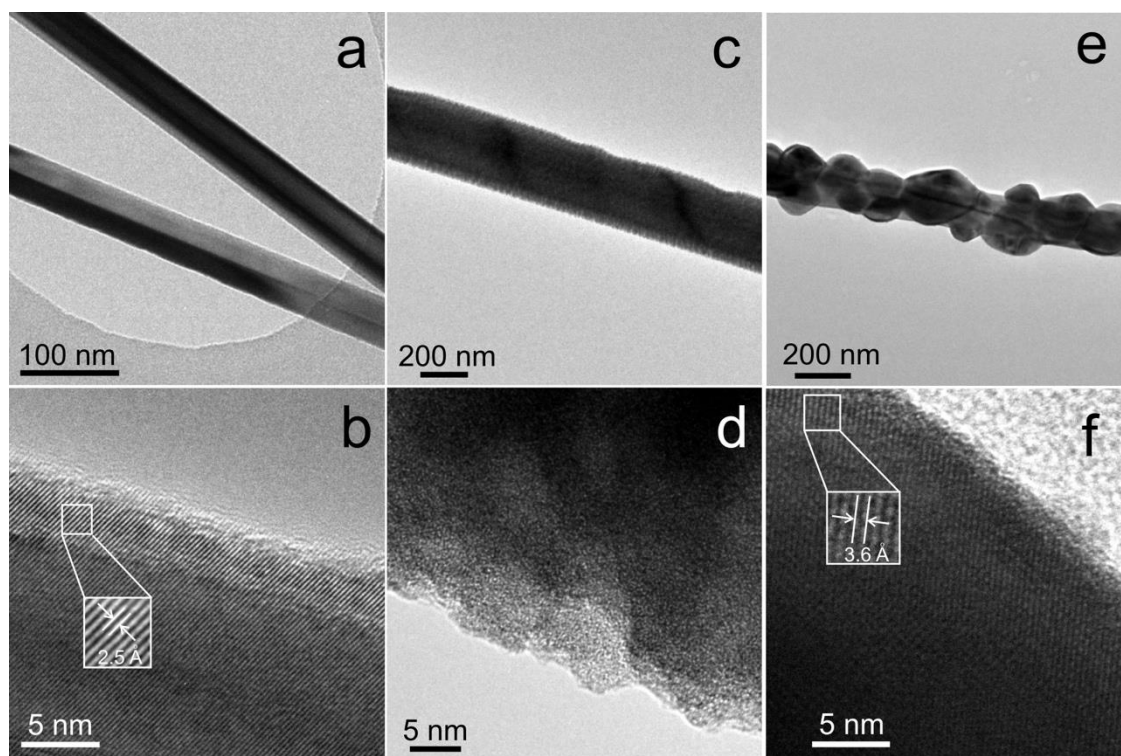


Fig. 5. TEM images at different magnifications of CuO NWs (a, b), core/shell CuO/WO₃ NWs (c, d), core/shell CuO/WO₃ NWs annealed at 650°C (e, f).

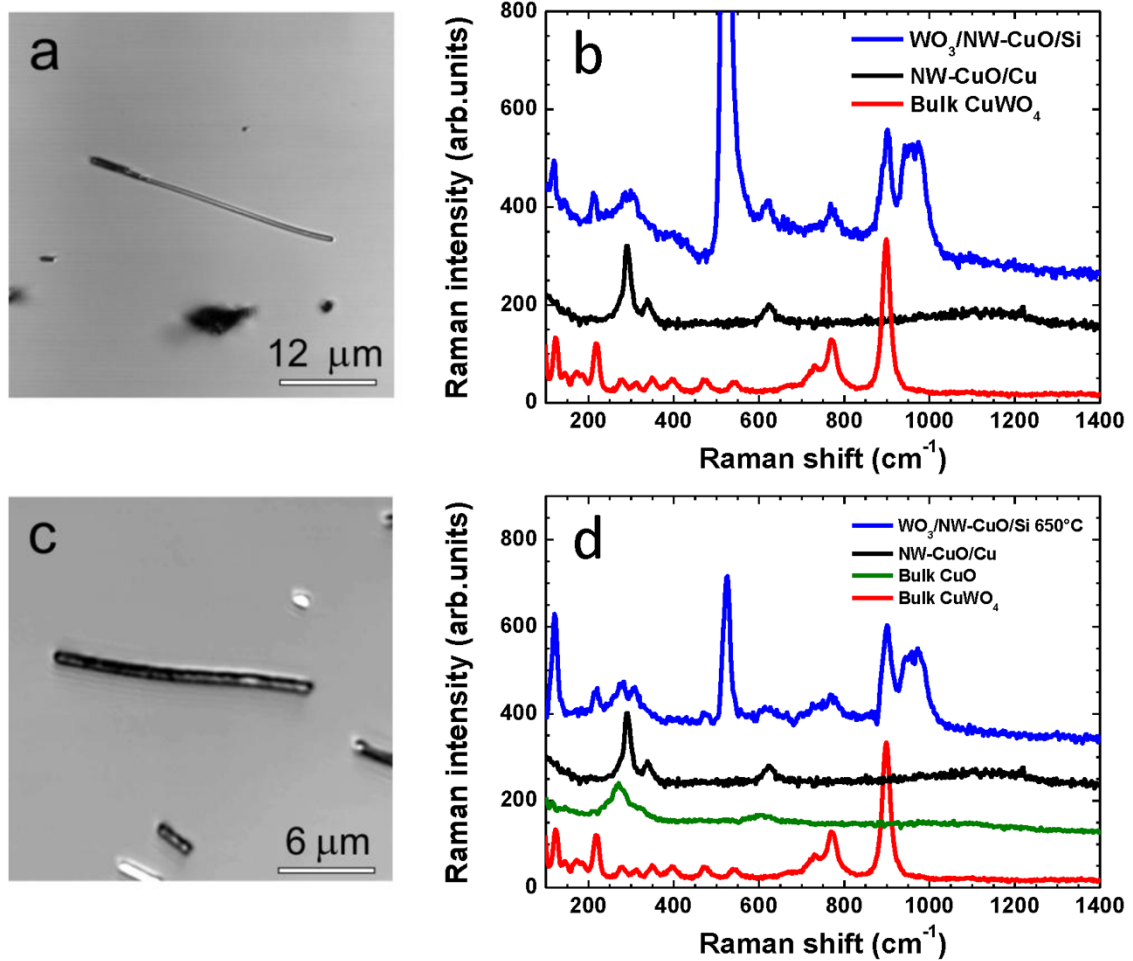


Fig. 6. Confocal microscope images and Raman scattering spectra of core/shell CuO/WO₃ nanowires (NWs) on silicon substrate before (a, b) and after (c, d) annealing at 650°C. Raman spectra of bulk CuO and CuWO₄ powders as well as of CuO NWs on Cu substrate (NW-CuO/Cu) are shown for comparison.

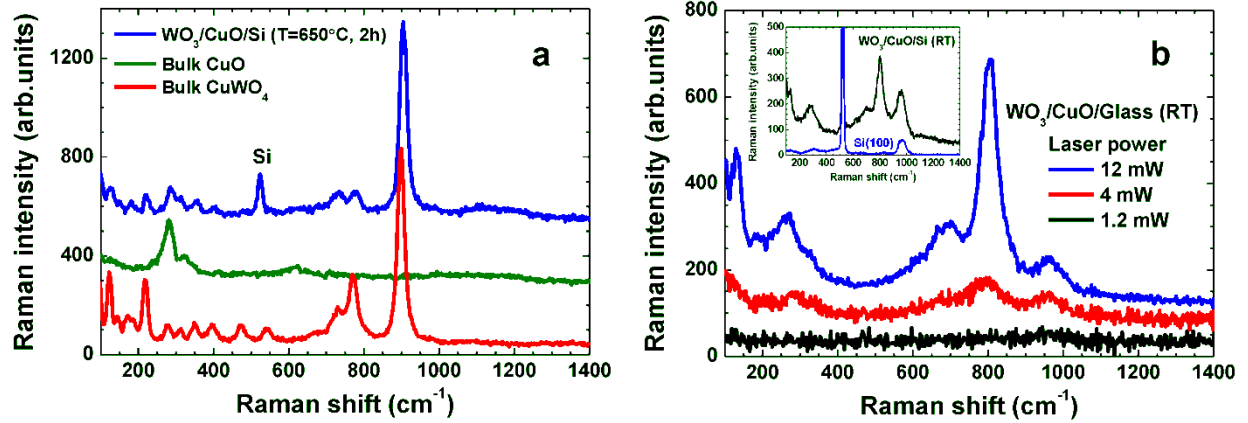


Fig. 7. (a) Raman scattering spectra of CuO/WO₃ thin film on silicon substrate after annealing at 650°C and of bulk CuO and CuWO₄ powders shown for comparison. (b) Raman scattering spectra of as-prepared CuO/WO₃ thin film on glass substrate as a function of laser power (Insert: Raman spectra of as-prepared CuO/WO₃ thin film on silicon substrate and pure silicon substrate).